

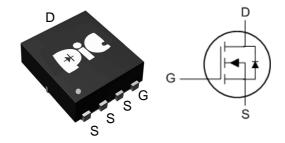
General Description

This PAN30SY86Y N-Channel enhancement mode power field effect transistor is the high density trench technology and this advanced technology can provide excellent Rds(On) performance and efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

Feature

- Super Low Gate Charge
- ●100% EAS Guaranteed
- Green Device Available
- ●Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

DFN5X6A-EP1



> Application

- ●DC/DC Primary Side Switch
- Industrial Synchronous
- Rectification Load Switch
- ●DC/DC Converters
- Power Management in Desktop Computer

> Absolute Maximum Ratings

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _G s	±20	V
Continuous Drain Current, V _{GS} @ 10V ^{1,6}	I _D @T _C =25°C	230	А
Continuous Drain Current, V _{GS} @ 10V ^{1,6}	I _D @T _C =100°C	147	А
Continuous Drain Current ¹	I _D @T _A =25°ℂ	39	А
Continuous Drain Current ¹	I _D @T _A =70°C	31	А
Pulsed Drain Current ²	I _{DM}	400	А
Single Pulse Avalanche Energy ³	EAS	420	mJ
Avalanche Current	las	41	А
Total Power Dissipation ⁴	P _D @T _C =25°C	89	W
Storage Temperature Range	T _{STG}	-55 to 150	$^{\circ}\mathbb{C}$
Operating Junction Temperature Range	TJ	-55 to 150	$^{\circ}\!\mathbb{C}$
Thermal Resistance Junction-Ambient ¹	Reja	62	°CM
Thermal Resistance Junction-Case ¹	Reuc	1.4	°CW



Electrical Characteristics (T_J=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V , Ip=250uA	30			V
Static Drain-Source On-Resistance2	Dagger	Vgs=10V , ID=20A		0.7	0.9	m0
	RDS(ON)	Vgs=4.5V , ID=20A		1.0	1.4	mΩ
Gate Threshold Voltage	VGS(th)	Vgs=Vps, Ip =250uA	1.2	1.7	2.2	V
Drain Source Leakage Current	Ipss	VDS=24V , VGS=0V , TJ=25°C			1	uA
Drain-Source Leakage Current	1055	Vbs=24V , Vgs=0V , TJ=55°C			5	
Gate-Source Leakage Current	Igss	Vgs=±20V , Vps=0V			±100	nA
Gate Resistance	Rg	Vps=0V , Vgs=0V , f=1MHz		1.4		Ω
Total Gate Charge (10V)	Qg			128		nC
Total Gate Charge (4.5V)	Qg	V 20V V 10V I- 20A		65		
Gate-Source Charge	Qgs	VDS=20V, VGS=10V, ID=20A		20		
Gate-Drain Charge	Qgd			28		
Turn-On Delay Time	T _{d(on)}			38		
Rise Time	Tr	V_{DD} =20 V , V_{GS} =10 V , R_{G} =1.5 Ω ,		22		
Turn-Off Delay Time	T _{d(off)}	ID=20A		115		ns
Fall Time	Tf			150		
Input Capacitance	Ciss			7427		
Output Capacitance	Coss	Vps=15V , Vgs=0V , f=1MHz		2930		рF
Reverse Transfer Capacitance	Crss			538		

Diode Characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous Source Current ^{1,6}	Is	V _G =V _D =0V , Force Current	I	I	100	Α
Diode Forward Voltage ²	V_{SD}	V_{GS} =0 V , I_{S} =1 A , T_{J} =25 $^{\circ}$ C			1.2	V
Reverse Recovery Time	t _{rr}	IF=20A , di/dt=100A/μs ,		75		nS
Reverse Recovery Charge	Qrr	TJ=25°C		114		nC

Note:

- 1 . Surface mounted on FR4 board using using 1 sq in pad size with 2OZ copper.
- 2 $^{\backprime}$ Pulsed test : pulse width \leqq 300us , duty cycle \leqq 2%
- $3 \cdot$ The EAS data shows Max. rating . The test condition is VDD=25V,VGs=10V,L=0.5mH,Ias=41A
- 4 $\cdot\,$ Ensure that the channel temperature does not exceed 150°C.
- $5 \cdot$ The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.
- 6 · Package limitation current is 100A.



> Typical Characteristics

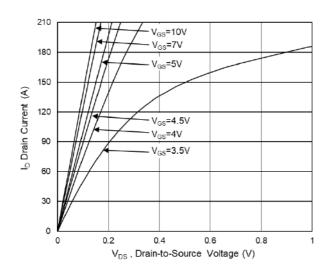


Fig.1 Typical Output Characteristics

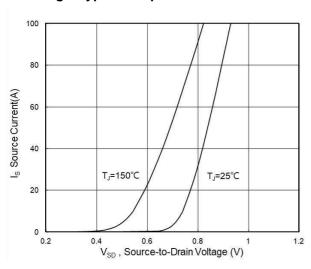


Fig.3 Source Drain Forward Characteristics

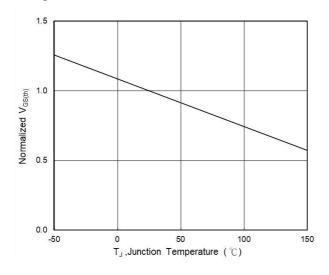


Fig.5 Normalized V_{GS(th)} vs T_J

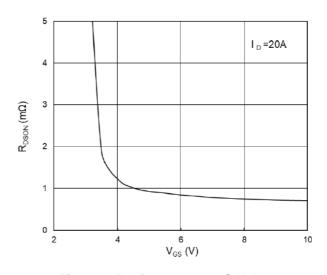


Fig.2 On-Resistance vs G-S Voltage

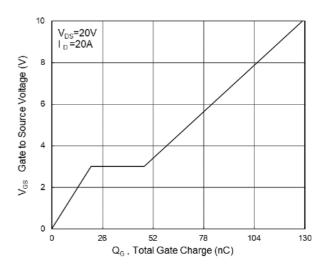


Fig.4 Gate-Charge Characteristics

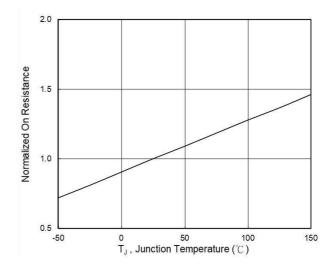
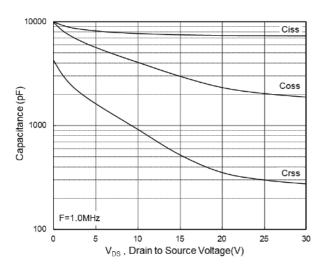


Fig.6 Normalized R_{DSON} vs T_J





1000
100
100
100us

Fig.7 Capacitance

Fig.8 Safe Operating Area

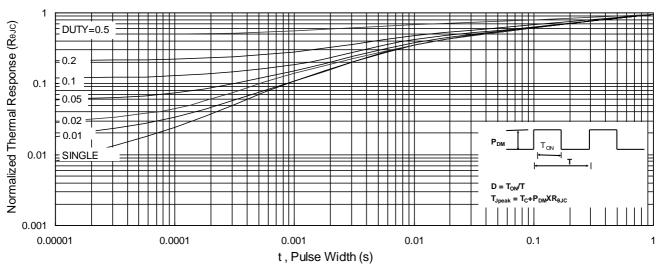


Fig.9 Normalized Maximum Transient Thermal Impedance

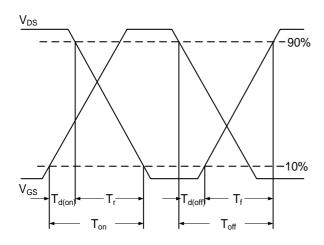


Fig.10 Switching Time Waveform

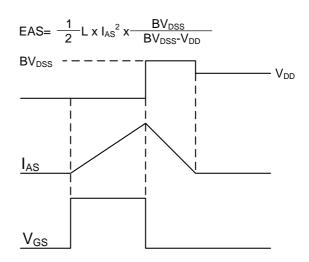
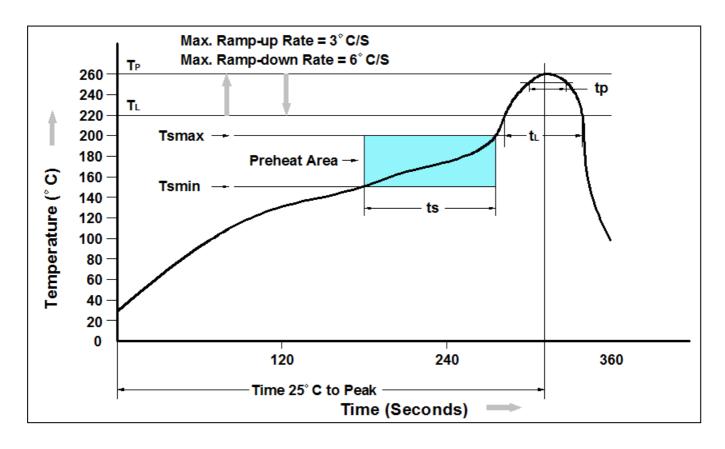


Fig.11 Unclamped Inductive Switching Waveform



Recommand IR Reflow Soldering Thermal Profile



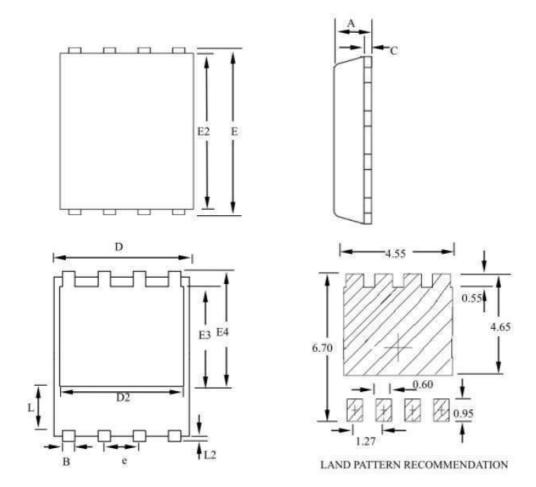
Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Average Ramp-up Rate (tLto tP)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (tL) Maintained Above (TL)	60 – 150 seconds
Peak Temperature	260°C +0°C / -5°C
Time (tP) within 5°C of actual Peak Temperature	30 seconds
Ramp-down Rate (TP to TL)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

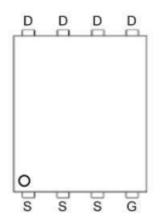
Ordering Information

Part Number	Description	Quantity
PAN30SY86Y	DFN5X6A-EP1 Reel	3000 pcs



Package Information (DFN5X6A-EP1)





SYMBOLS	MBOLS MILLIMETERS		INCHES			
O T MIDOLO	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	7577	1.20	0.031	0.775	0.047
В	0.30	(##)	0.51	0.012	1000	0.020
С	0.15	34005 54005	0.35	0.006	-	0.014
D	4.80	1243	5.30	0.189	0.2250	0.209
D2	3.61	753	4.35	0.142		0.171
Е	5.90	(##)	6.35	0.232	0.00	0.250
E2	5.42	(24)	5.90	0.213	N#F	0.232
E3	3.23	-	3.90	0.127		0.154
E4	3.69	1777	4.55	0.145		0.179
L	0.61	3000	1.80	0.024	(1000)	0.071
L2	0.05	443	0.36	0.002	2440	0.014
е		1.27		-	0.050	





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